NSN 5962-01-578-1827

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-578-1827

Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Current Rating Per Characteristic:
50.00 milliamperes output
Product Name:
Cmos static ram 256k (32k x 8-bit)
Memory Device Type:
Ram
Memory Capacity:
32k x 8
Special Features:
High-speed address-chip select time; low-power operation; battery backup operation-2v data retention; produced with advanced
high-performance cmos technology; input and output directly ttl-compatible; available in standard 28-pin (300 or 600 mil) ceramic dip,
28-pin (600 mil) plastic dip, 28-pin (300 mil) soj and 32-pin lcc; military product compliant to mil-std-883, class b
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
A458a0